



单向硅整流桥堆

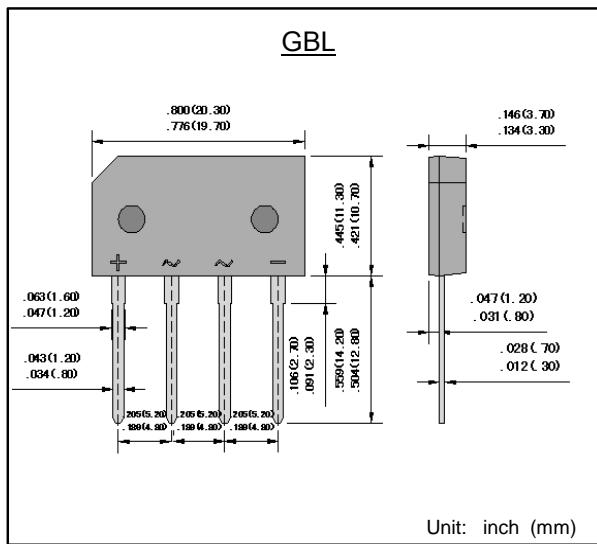
反向电压 50 ~ 1000 V

正向电流 4.0 A

Single-phase Silicon Bridge Rectifiers

Reverse Voltage 50 ~ 1000 V

Forward Current 4.0 A

**特征 Features**

- 反向漏电流低 Low reverse leakage
- 正向浪涌承受能力强 High forward surge capability
- 高信赖性 High reliability
- 玻璃钝化芯片 Glass passivated chip
- 引线和管体皆符合RoHS标准 Lead and body according with RoHS standard
- 型号后缀“-F”标记无卤素产品 Green compound with suffix "-F" on Marking

机械数据 Mechanical Data

- 封装外形: GBL 塑封 Case: GBL Molded plastic
- 环氧树脂 : UL易燃等级: 94V-0
Epoxy: UL 94V-0 rate flame retardant
- 引脚 : 镀锡,无铅 Lead: Pure tin plated, lead free
- 安装位置: 任意 Mounting Position: Any

最大值和特性 TA = 25°C 除非另有规定。**Maximum Ratings & Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

参数 Parameter	符号 Symbols	GBL 401	GBL 402	GBL 403	GBL 404	GBL 405	GBL 406	GBL 407	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
最大均方根电压 Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
最大直流阻断电压 Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
最大正向平均整流电流 Maximum average forward rectified current	I _{F(AV)}					4.0			A
正向不重复浪涌电流 8.3 ms 单一正弦半波 Non-repetitive peak forward surge current 8.3 ms singlehalf sine-wave	I _{FSM}					120			A
熔断系数 t ≤ 8.3 ms Current squared time t ≤ 8.3 ms	I ² t				60				A ² S
最大正向电压 @IF=2.0A Maximum forward voltage	V _F				1.0				V
最大反向电流 @V _{DC} TA = 25°C Maximum reverse current	I _R				5				μA
典型热阻 Typical thermal resistance (Note 1、2) R _{θJA}	R _{θJA}			47					°C/W
	R _{θJL}			10					
工作结温和存储温度 Operating junction and storage temperature range	T _J , T _{STG}			-55 --- +150					°C

备注 Note:

- 1) 安装在PCB板上，从PN结到环境的热阻。
1) Thermal resistance from junction to ambient, PCB mounted.
- 2) 安装在PCB板上，从PN结到引脚的热阻。
2) Thermal resistance from junction to lead, PCB mounted.



特性曲线 Characteristic Curves

